A practical approach to detect turn to turn shorts during superconductive magnet fabrication

Giovanni Gabrielli

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Introduction

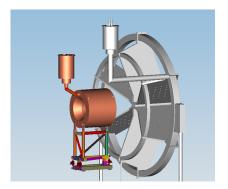
CLAS12 turn to turn short detector

High resolution DC resistance

CLAS12 for Hall B experiment

Six superconductive magnets generate a toroidal magnetic field in order to deviate the debris coming from collisions between particles.

Each magnet is a double layered Nb_3Sn coil with 117 turns per layer, winded, clamped and cured in Technical Division.





High resolution DC resistance

Turn to turn shorts



What is a short?

• It is an electrical contact between two consecutive turns



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Turn to turn shorts



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Turn to turn shorts



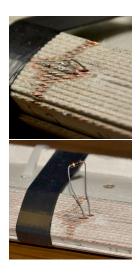
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Turn to turn shorts



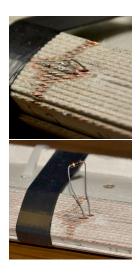
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• Simulated with resistors or wires (see pictures)



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Preliminary study

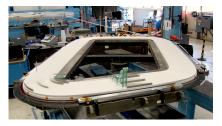
CLAS12 turn to turn short detector

Task

Detect turn to turn shorts, both hard and as soft as possible.

Problems:

Solution:





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Preliminary study

CLAS12 turn to turn short detector

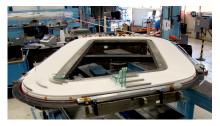
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Problems:

Novel approach

Solution:





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CLAS12 turn to turn short detector

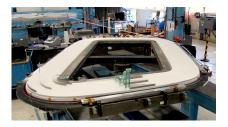
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Detect turn to turn shorts, both hard and as soft as possible.

Problems:

- Novel approach
- TL theory doesn't work

Solution:



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Preliminary study

CLAS12 turn to turn short detector

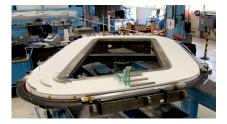
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CLAS12 turn to turn short detector

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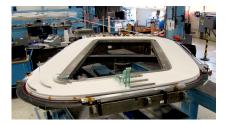
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Solution:

• AC steady state, high frequency, high impedance



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Preliminary study

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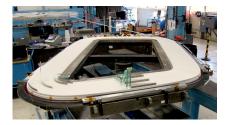
Detect turn to turn shorts, both hard and as soft as possible.

Problems:

- Novel approach
- TL theory doesn't work
- Very low DC resistance

Solution:

- AC steady state, high frequency, high impedance
- Significant voltage drop between turns



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Preliminary study

AC impedance analysis

Setup:

• Inductive zone: $|Z| \approx \omega L$, rising with frequency



Figure: Double layered unclamped coil AC impedance



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Preliminary study

AC impedance analysis

Setup:

- Inductive zone: $|Z| \approx \omega L$, rising with frequency
- Each turn has higher impedance

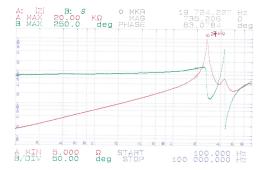


Figure: Double layered unclamped coil AC impedance



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Preliminary study

AC impedance analysis

Setup:

- Inductive zone: $|Z| \approx \omega L$, rising with frequency
- Each turn has higher impedance
- Softer short are more easily detectable

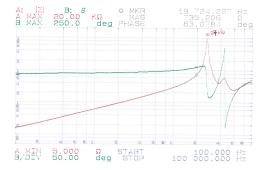


Figure: Double layered unclamped coil AC impedance



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Preliminary study

AC impedance analysis

Setup:

- Inductive zone: $|Z| \approx \omega L$, rising with frequency
- Each turn has higher impedance
- Softer short are more easily detectable
- High frequency needed

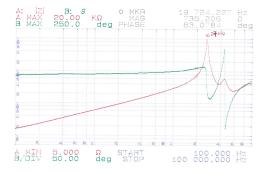


Figure: Double layered unclamped coil AC impedance

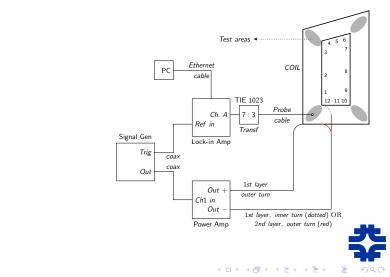


Setup:

Setup

CLAS12 turn to turn short detector

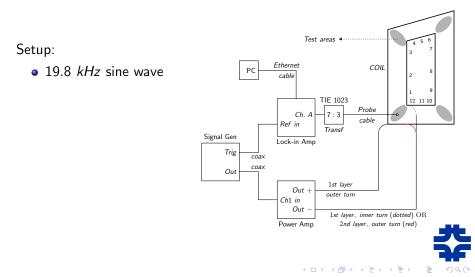
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Setup

CLAS12 turn to turn short detector

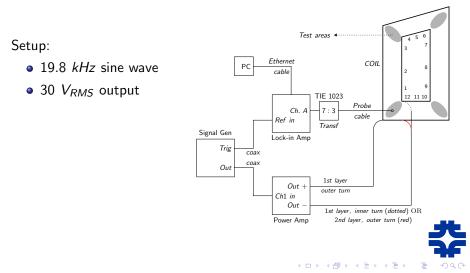
High resolution DC resistance



Setup

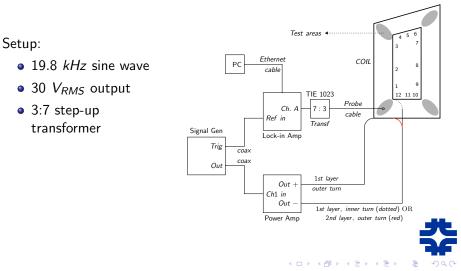
CLAS12 turn to turn short detector

High resolution DC resistance



CLAS12 turn to turn short detector

High resolution DC resistance



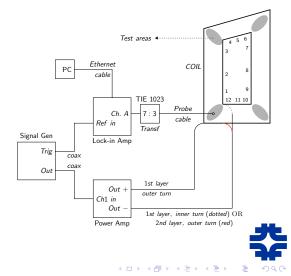
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General setup

Setup:

- 19.8 kHz sine wave
- 30 V_{RMS} output
- 3:7 step-up transformer
- Automatic data acquisition: LabView driver



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Transformer

Transformer:

• Required by the Lock-in Amplifier





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Transformer

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- Low CMRR, huge offset





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High resolution DC resistance

Transformer

Transformer:

- Required by the Lock-in Amplifier
- Low CMRR, huge offset
- "Walking effect"
- Parasitic asymmetric capacitive coupling





CLAS12 turn to turn short detector

High resolution DC resistance

Transformer

Transformer:

- Required by the Lock-in Amplifier
- Low CMRR, huge offset
- "Walking effect"
- Parasitic asymmetric capacitive coupling
- Handmade transformer: more distant coils, high frequency wire, negligible parasitic effects



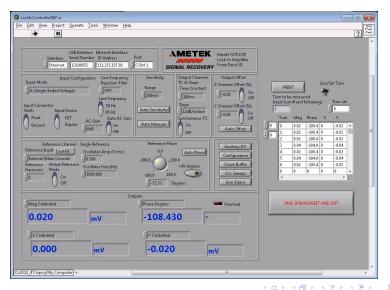


Setup

CLAS12 turn to turn short detector

High resolution DC resistance

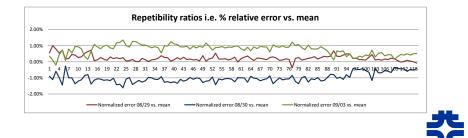
LabView Driver



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 A few scannings of all turns, one position (corner 1-12), to see repeatability, that is the precision of the method



Setup

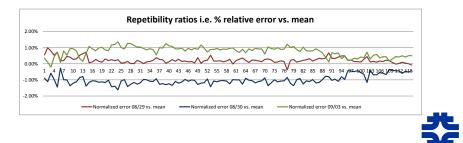
CLAS12 turn to turn short detector

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Procedure

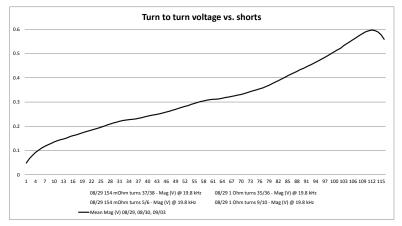
- A few scannings of all turns, one position (corner 1-12), to see repeatability, that is the precision of the method
- Scannings with different shorts to see position and amount of turn to turn voltage losses, that is the sensitivity and resolution of the method.



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Non shorted coil voltage curve

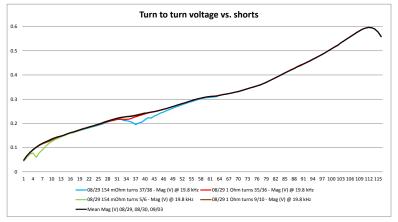


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Non shorted vs. shorted coil voltage curves



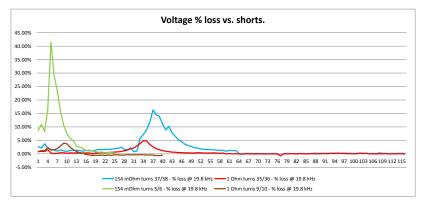
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Voltage losses



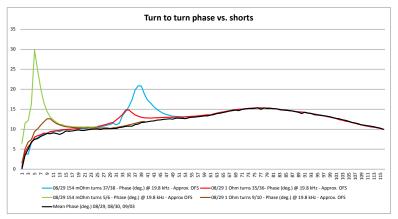


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Non shorted vs. shorted coil phase curves

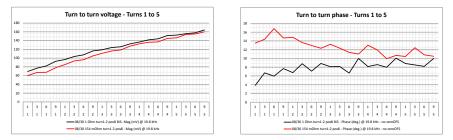




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4 position method

In the very first turns it is harder to see a sharp loss with a smooth bending by its sides. A 4-position scanning can help increase the resolution.



NB: with low SNR, the help of the phase is fundamental.

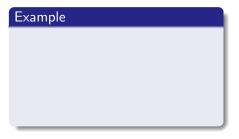


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High resolution DC resistance

Conclusions and problems

Resolution: up to 1 Ω in middle turns, up to a few hundreds $m\Omega$ in the first 5. But:



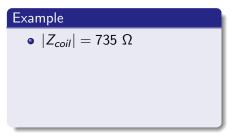


CLAS12 turn to turn short detector

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High resolution DC resistance

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Example • $|Z_{coil}| = 735 \Omega$ • $|Z_{turn}| \approx \frac{|Z_{coil}|}{117 \cdot 2} \approx 3 \Omega$



High resolution DC resistance

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Resolution: up to 1 Ω in middle turns, up to a few hundreds $m\Omega$ in the first 5. But:

Example • $|Z_{coil}| = 735 \Omega$ • $|Z_{turn}| \approx \frac{|Z_{coil}|}{117.2} \approx 3 \Omega$ • $|Z_{short}| = 150 \ m\Omega$



CLAS12 turn to turn short detector

High resolution DC resistance

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Conclusions and problems

Resolution: up to 1 Ω in middle turns, up to a few hundreds $m\Omega$ in the first 5. But:

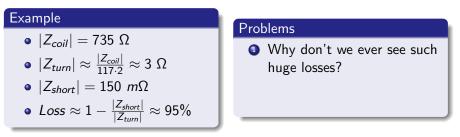
Example • $|Z_{coil}| = 735 \Omega$ • $|Z_{turn}| \approx \frac{|Z_{coil}|}{117 \cdot 2} \approx 3 \Omega$ • $|Z_{short}| = 150 \ m\Omega$ • $Loss \approx 1 - \frac{|Z_{short}|}{|Z_{turn}|} \approx 95\%$

CLAS12 turn to turn short detector

High resolution DC resistance

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High resolution DC resistance

Conclusions and problems

Resolution: up to 1 Ω in middle turns, up to a few hundreds $m\Omega$ in the first 5. But:

Example

•
$$|Z_{coil}| = 735 \ \Omega$$

•
$$|Z_{turn}| \approx \frac{|Z_{coil}|}{117 \cdot 2} \approx 3 \ \Omega$$

•
$$|Z_{short}| = 150 \ m\Omega$$

• Loss
$$\approx 1 - \frac{|Z_{short}|}{|Z_{turn}|} \approx 95\%$$

Problems

- Why don't we ever see such huge losses?
- Why should a short influence even the nearest turns?

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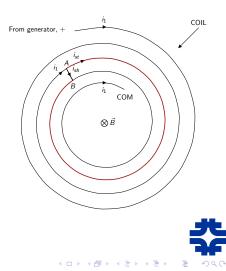


High resolution DC resistance

Zero model for currents in a shorted coil

Zero model for currents in a shorted coil

• Shorted turn (in red) is "bypassed"

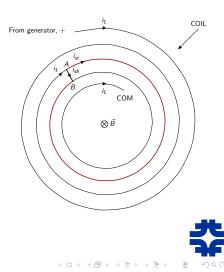


High resolution DC resistance

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- Shorted turn (in red) is "bypassed"
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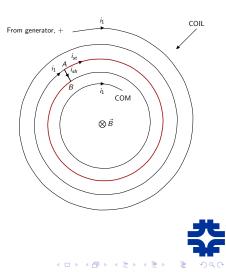
CLAS12 turn to turn short detector

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- High i_{st} < 0 generates high B_{st} < 0 to compensate B_{tot}



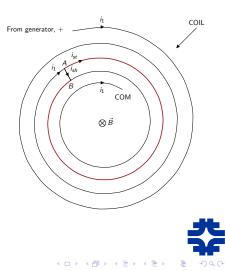
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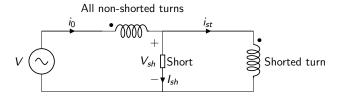
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- High *i_{st}* < 0 generates high *B_{st}* < 0 to compensate *B_{tot}*
- High *i_{sh}* gives relatively high voltage drop *V_{sh}*



High resolution DC resistance

Zero model for currents in a shorted coil

What (almost) really happens



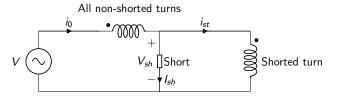


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What (almost) really happens



• Mutual induction: the shorted coil is the "secondary"

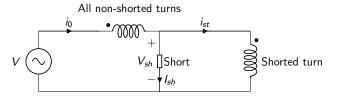


CLAS12 turn to turn short detector

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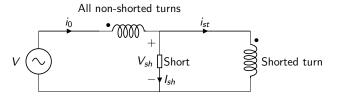
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Zero model for currents in a shorted coil

What (almost) really happens



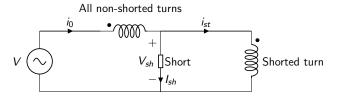
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Zero model for currents in a shorted coil

What (almost) really happens



- Mutual induction: the shorted coil is the "secondary"
- V_{st} is still positive because of Lenz's Law
- $B_{st} < 0$ influences mostly the nearest turns

Despite this is a zero model, experimental data fit this theoretical result with good approximation.



Setup

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High Resolution DC resistance measure

Task

Measure small DC resistances with as high precision as possible.



High resolution DC resistance $\bullet \circ \circ \circ \circ \circ \circ$

High Resolution DC resistance measure

Task

Measure small DC resistances with as high precision as possible.

• 4-wire measurement with 81/2 digits resolution multimeter 3458A from Agilent: less than 4 significant digit for a 1 Ω shunt.





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CLAS12 turn to turn short detector

High resolution DC resistance $\bullet \circ \circ \circ \circ \circ \circ$

High Resolution DC resistance measure

Task

Measure small DC resistances with as high precision as possible.

- 4-wire measurement with 81/2 digits resolution multimeter 3458A from Agilent: less than 4 significant digit for a 1 Ω shunt.
- "Enhanced 4W" needed: higher currents for very low resistances.



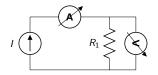


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Measuring the shunts

• 3458A as ammeter, $I \approx 1 A$ imposed, measured $R_1 \approx 1 \Omega$ with 5 significant digits.



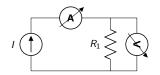


CLAS12 turn to turn short detector

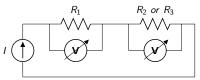
High resolution DC resistance 000000

Measuring the shunts

• 3458A as ammeter, $I \approx 1 A$ imposed, measured $R_1 \approx 1 \Omega$ with 5 significant digits.



2 3458A as voltmeter on R_1 as shunt, $I \approx 1$ A imposed, measured $R_2 \approx 10 \ m\Omega$ and $R_3 \approx 1 \ m\Omega$ with 4 and 3 significant digits.



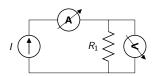
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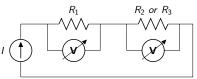
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High resolution DC resistance 000000

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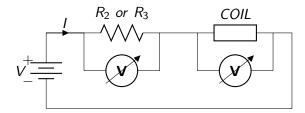


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The same way with just R₂ and R₃ to double check their ratio at higher currents.

Measuring the coil

 Coil as load, R₂ and R₃ as shunts, currents from 1 to 10 A. Measured R_{coil} with no less than 3 significant digits. NB: Voltage source used because current source did not work with reactive loads.





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Results



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High resolution DC resistance

Im avg	Va avg	Vb avg	Vc avg	Ra avg	Rb avg	Rc avg
1.00538	1.00577	10.02065	0.9955	1.000387913	9.967027393	0.99017287
0.901365	0.90175	8.9885	0.8928	1.00042713	9.972097874	0.990497745
0.8944	0.89479	8.909	0.885	1.000436047	9.960867621	0.989490161
0.89587		8.9345	0.8884		9.972987152	0.991661737
			Average:	1.00041703	9.967839188	0.99066020
			St. Dev.	0.00002091	0.003986671	0.00074192
			% St. Dev.	0.002090%	0.039995%	0.074891%
			Final values:	1.0004	9.968	0.991



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Small test coil

Vshunt (mV)	Rshunt (mOhms)	I meas (A)	Vcoil (mV)	R coil (mOhms)
10.325	9.968	1.035814607	26.919	25.98824136
20.831	9.968	2.089787319	54.315	25.99068312
40.791	9.968	4.092195024	106.33	25.98361011
70.705	9.968	7.093198234	184.3	25.98263772
102.76	9.968	10.30898876	267.95	25.99188011
1.025	0.991	1.034308779	26.876	25.98450341
2.0755	0.991	2.094349142	54.397	25.97322428
4.062	0.991	4.09889001	106.46	25.97288528
7.045	0.991	7.108980827	184.65	25.97418737
10.224	0.991	10.31685166	268.1	25.98660994

Average:	25.98284627
St. Dev.	0.00675612
% St.Dev.	0.0260%

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R: 25.98 4 significant digits.



Results

CLAS12 coil

CLAS12 turn to turn short detector

High resolution DC resistance $\circ\circ\circ\circ\circ\circ$

Vshunt (mV)	Rshunt (mOhms)	I meas (A)	Vcoil (V)	R coil (mOhms)
10.767	9.968	1.080156501	0.9124	844.692412
26.497	9.968	2.65820626	2.2447	844.4416198
65.198	9.968	6.540730337	5.5207	844.0494739
102.34	9.968	10.26685393	8.664	843.8807114
1.113	0.991	1.123107972	0.9484	844.4424079
2.589	0.991	2.612512614	2.205	844.0150637
6.211	0.991	6.26740666	5.2891	843.9056674
10.355	0.991	10.44904137	8.8176	843.8668856

Average:	844.1617802
St. Dev.	0.2967168
% St.Dev.	0.0351%

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R:

844

3 significant digits, but St. Dev is much less than half of the last digit.



A practical approach to detect turn to turn shorts during superconductive magnet fabrication

Giovanni Gabrielli

Supervisor: Luciano Elementi Coordinator: Emanuela Barzi Fermilab National Accelerator Laboratory

September 27, 2013



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